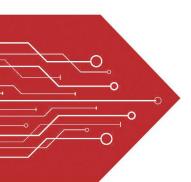
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet



DIGITAL TRANSISTOR (NPN)

FEATURES

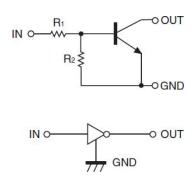
- Built-in bias resistors enable the

 configuration of an inverter circuit without

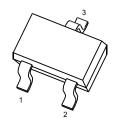
 connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors
 with complete isolation to allow negative biasing
 of the input. They also have the advantage of almost completely
 eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



Equivalent Circuit



· PIN

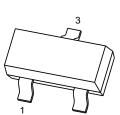


SOT-323

IN
 GND

3. OUT

DTC143EUA-MS



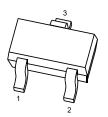
DTC143ECA-MS

1. IN

2. GND

3. OUT

SOT-23

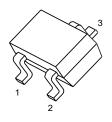


1. IN

2. GND

3. OUT

DTC143EE-MS SOT-523



1. IN

2. GND

3. OUT

DTC143EKA-MS SOT-23-3L



MAXIMUM RATINGS(Ta=25℃ unless otherwise noted)

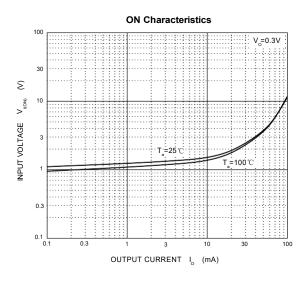
Symbol	Parameter	DTC143				Unit			
Cymbol	raidiffeter		EE-MS	EUA-MS	ECA-MS	EKA-MS			
V _{cc}	Supply Voltage	50			V				
V _{IN}	Input Voltage	-10∼+30				V			
lo	Output Current	100				mA			
P _D	Power Dissipation		150	200	200	200		mW	
Tj	Junction Temperature	150		$^{\circ}$					
T _{stg}	Storage Temperature	-55∼+150		$^{\circ}$					

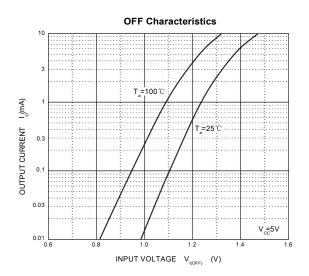
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

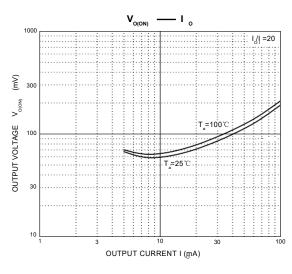
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =5V,I _O =100μA	0.5			V
Input voltage	V _{I(on)}	Vo=0.3V,Io=20mA			3	V
Output voltage	V _{O(on)}	I _O /I _I =10mA/0.5mA			0.3	V
Input current	I	V _I =5V			1.8	mA
Output current	I _{O(off)}	V _{CC} =50V,V _I =0			0.5	μA
DC current gain	Gı	V _O =5V,I _O =10mA	20			
Input resistance	R ₁		3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁		0.8	1	1.2	
Transition frequency	f⊤	V ₀ =10V,I ₀ =5mA,f=100MHz		250		MHz

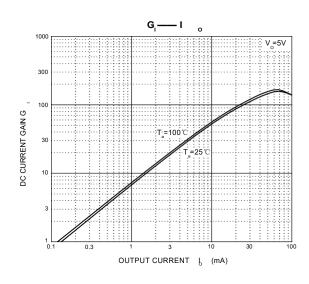


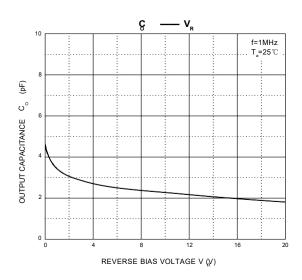
Typical Characteristics

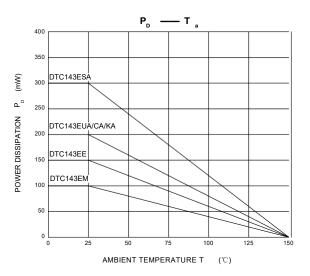




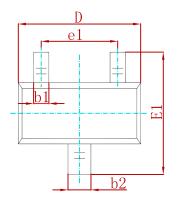


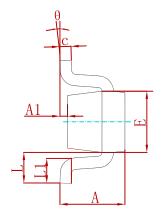


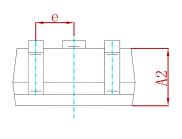






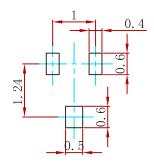






Comple ed	Dimensions	In Millimeters Dimensions I		s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
С	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
е	0.500	TYP.	0.020	TYP.
e1	0.900	1.100	0.035	0.043
L	0.400	REF.	0.016	REF.
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

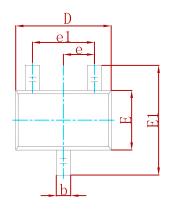
Suggested Pad Layout

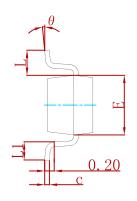


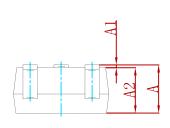
- 1.Controlling dimension:in millimeters.2.General tolerance:±0.05mm.3.The pad layout is for reference purposes only.

P/N	PKG	QTY
DTC143EE-MS	SOT-523	3000



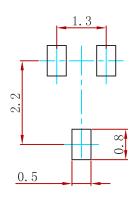






Symbol	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
Е	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650) TYP	0.026	6 TYP
e1	1.200	1.400	0.047	0.055
L	0.525	REF	0.021	REF
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

Suggested Pad Layout

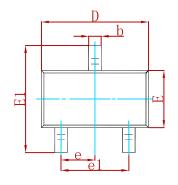


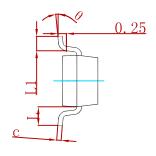
Note:

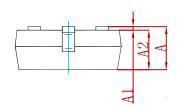
- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

P/N	PKG	QTY
DTC143EUA-MS	SOT-323	3000



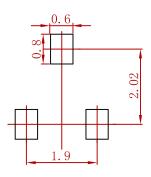






Symbol	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
Е	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.950) TYP	0.037	7 TYP
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022	2 REF
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

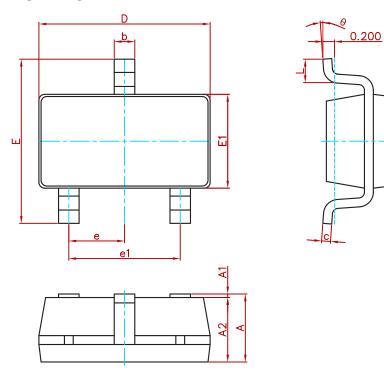
Suggested Pad Layout



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

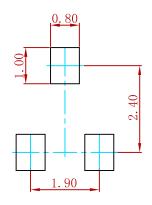
P/N	PKG	QTY
DTC143ECA-MS	SOT-23	3000





Symbol	Dimensions In	n Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950(BSC)	0.037((BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

P/N	PKG	QTY
DTC143EKA-MS	SOT-23-3L	3000



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